

MM5600



40 Gbps DPDT Differential Switch with Integrated Driver



Product Overview

Description

Menlo Micro has developed a DPDT switch for high-speed differential signal switching. The MM5600 is based on Menlo’s Ideal Switch® technology and can operate up to 40 Gbps for digital signaling applications, or high-performance RF applications up to 20 GHz. The MM5600 has low insertion loss, fast switching speed, internal ESD diodes, and can operate with greater than three billion switching cycles.

The MM5600’s integrated driver is controlled by a serial-to-parallel interface that drives the high voltage gate lines of the switches. The design also offers two separate single-ended ports and a considerable 90% reduction in size when compared with comparable EM relay solutions. An external +5 VDC logic supply and high voltage +89 VDC bias source is required for operation of the internal switch driver.

Features

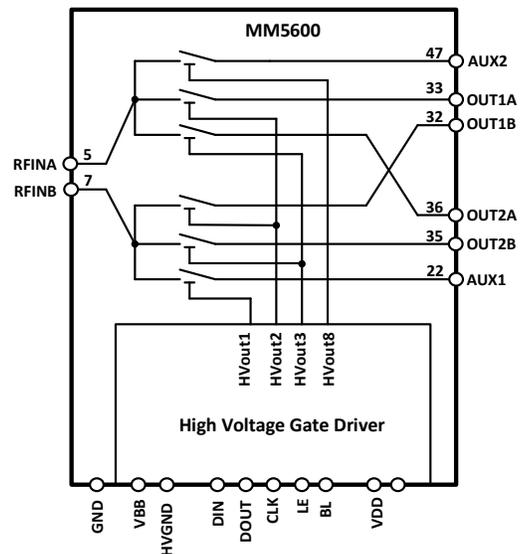
- DC to 20 GHz range, up to 40 Gbps
- Low Insertion Loss
- Integrated driver eliminates the requirement for an external gate driver
- Independently controlled dual loopback ports
- High Reliability: Greater than 3 billion switching operations

Applications

- Differential High-Speed Switching
- ATE-Device Interface Boards
- High-Speed Computer Peripheral Interfaces

Markets

- Differential Component Testing
- Differential Signal Routing
- Test and Measurement



Electrical Specifications

Operating Characteristics

Absolute Maximum Ratings

Exceeding the maximum ratings as listed in [Table 1](#) below may reduce the reliability of the device or cause permanent damage. Operation of the MM5600 should be restricted to the limits indicated in the recommended operating conditions listed in [Table 2](#).

Electrostatic Discharge (ESD) Safeguards

The MM5600 is a Class 1B ESD device. When handling the MM5600, observe precautions as with any other ESD sensitive device. Do not exceed the voltage ratings specified in [Table 1](#).

Power Sequencing

The following power sequence is recommended to avoid latch-up.

- Power-Up: Apply V_{DD} , set all inputs to known state, apply V_{BB} .
- Power-Down: Remove V_{BB} , remove all inputs, remove V_{DD} .

The high voltage supply (V_{BB}) may be applied and removed as required when V_{DD} is present. V_{BB} voltage should not drop below V_{DD} or float during operation.

Table 1. Absolute Maximum Ratings¹

Parameter	Minimum	Maximum	Unit
Max RF Input Power @ 6 GHz Single Ended	—	+33	dBm
Open State Voltage Rating / Switch OUTx to INx	-150	150	V
Open State Voltage OUTx, INx to GND, V _{BB} pin to GND Potential	-150	150	V
Closed State Voltage V _{BB} to OUTx, INx, GND	-100	100	V
Hot Switching Voltage ^{2,3}	-0.5	0.5	V
DC Carry Current Rating / Switch	—	100	mA
Driver Voltage Supply V _{DD}	-0.5	+6	V
High Voltage Gate Driver Supply V _{BB}	—	+100	V
Driver Logic Input Levels	-0.5	V _{DD} +0.5	V
Storage Temperature Range ⁴	-65	+150	°C
ESD Rating HBM Driver Pins ⁵	—	750	V
ESD Rating HBM RF I/O Pins ⁶	—	500	V

Notes:

- All parameters must be within recommended operating conditions. Maximum DC and RF power can only be applied during the on-state condition (cold-switched condition).
- For hot-switching, differential voltage across switch terminals must be less than or equal to 0.5 V and each switch port must within +/-0.5 V of RF ground.
- RF pins must not be allowed to electrically float during switch operation. See section [Floating Node Restrictions](#) for details on avoiding floating nodes.
- See section [Storage and Shelf Life](#) for more information on shelf and floor life.
- Driver pins include: CLK, BL, LE, D_{IN}, D_{OUT}, V_{BB}, V_{DD}.
- RF I/O pins include: RFINA, RFINB, OUT1A, OUT1B, OUT2A, OUT2B, AUX1, AUX2.

Table 2. Recommended Operating Conditions

Parameter	Min	Typical	Max	Unit
Driver Logic Supply Voltage (V _{DD})	4.5	5.0	5.5	V
High-Voltage Bias Supply Voltage (V _{BB}) ¹	88	89	90	V _{DC}
Operating Temperature Range	-40	—	+85	°C

Notes:

- Note that High-Voltage Bias must be applied to V_{BB}. It is not part of the integrated driver.

Electrical Characteristics

All specifications are valid over full V_{BB} range and operating temperature range unless otherwise noted.

Table 3. RF Characteristics

Parameter	Minimum	Typical ¹	Maximum	Unit
Operating Frequency Range				
Single-Ended mode	DC	—	10	GHz
Differential mode	DC	—	10	GHz
Max RF Power @ 3 GHz²	—	—	33	dBm
Insertion Loss				
Single-Ended mode @ 10 GHz	—	1.3	—	dB
Input / Output Return Loss				
Single-Ended mode @ 10 GHz	—	11	—	dB
Isolation				
Single-Ended mode @ 10 GHz	—	24	—	dB
Third-Order Intercept Point (IP3)³	—	77	—	dBm
Second Harmonic (H2)⁴	—	-102	—	dBc
Third Harmonic (H3)⁵	—	-101	—	dBc

Notes:

1. Typical specifications represent the parametric norm.
2. Single Ended only 50 Ohms Measured at +85°C.
3. Measured at +25°C and 37dBm input power of the fundamental tones.
4. Measured at 2 GHz fundamental frequency and 33 dBm input power.
5. Measured at 2 GHz fundamental frequency and 33 dBm input power.

Signal Integrity Differential Performance

Test conditions for the differential eye-diagram performance measurements are listed below:

- Test pattern: $2^{15}-1$ NRZ
- Differential RF input amplitude: 1000 mVpp
- Measurements performed at 32 Gbps and 40 Gbps
- Tests performed at ambient temperature
- RF connector, traces, and cables are de-embedded
- Testing performed on MM5600 EVK

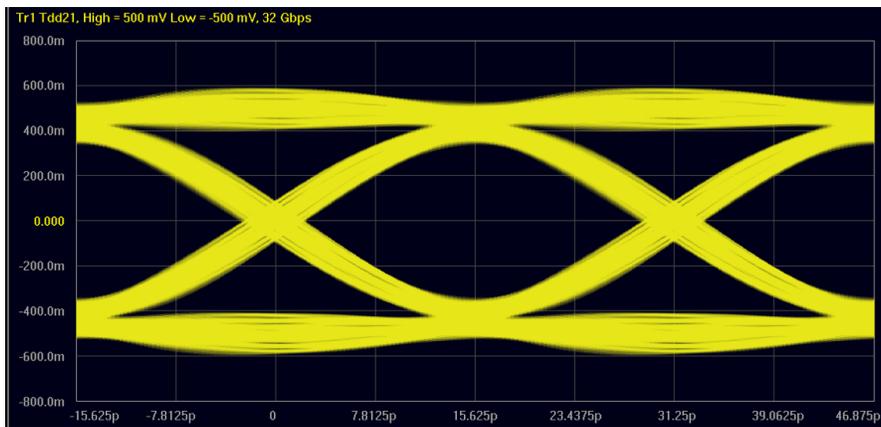


Figure 1. 32 Gbps OUT1 ON Eye Diagram

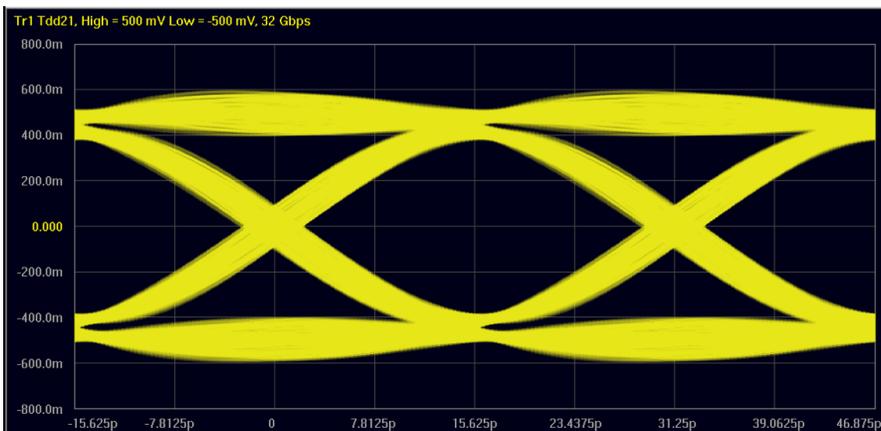


Figure 2. 32 Gbps OUT2 ON Eye Diagram

Table 4. 32 Gbps Eye-Diagram Measurements

Test Cases	Bit Rate (Gbps)	Eye Height (ps)	Eye Width (ps)	Jitter (Peak to Peak, ps)	Rise Time (10%-90%, ps)	Fall Time (90%-10%,ps)
Output 1 ON	32	603.2	23.48	5.66	22.03	22.04
Output 2 ON	32	646.3	23.46	5.59	21.24	21.27

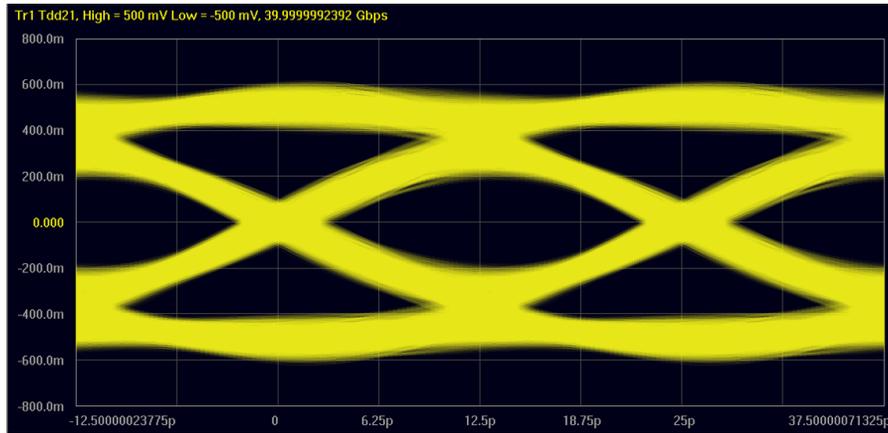
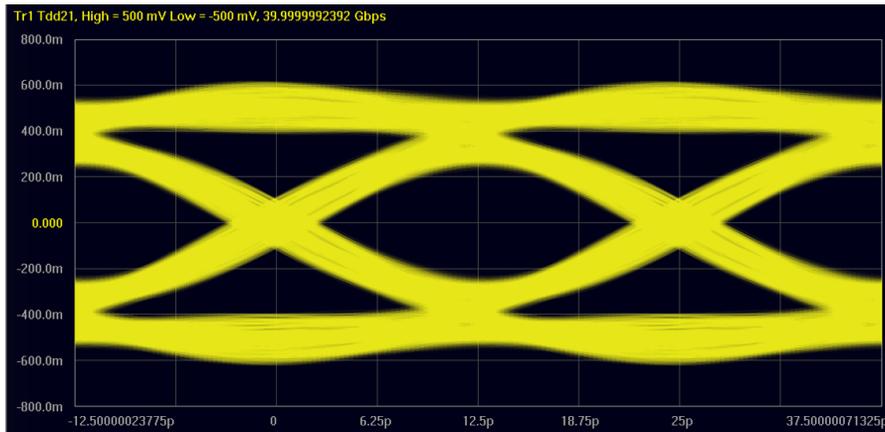

Figure 3. 40 Gbps OUT1 ON Eye Diagram

Figure 4. 40 Gbps OUT2 ON Eye Diagram

Table 5. 40 Gbps Eye-Diagram Measurements

Test Cases	Bit Rate (Gbps)	Eye Height (ps)	Eye Width (ps)	Jitter (Peak to Peak, ps)	Rise Time (10%-90%, ps)	Fall Time (90%-10%,ps)
Output 1 ON	40	224.5	16.33	6.85	20.02	20.02
Output 2 ON	40	310.0	16.07	6.61	19.97	19.93


Figure 5. Single-ended Insertion Loss / S21

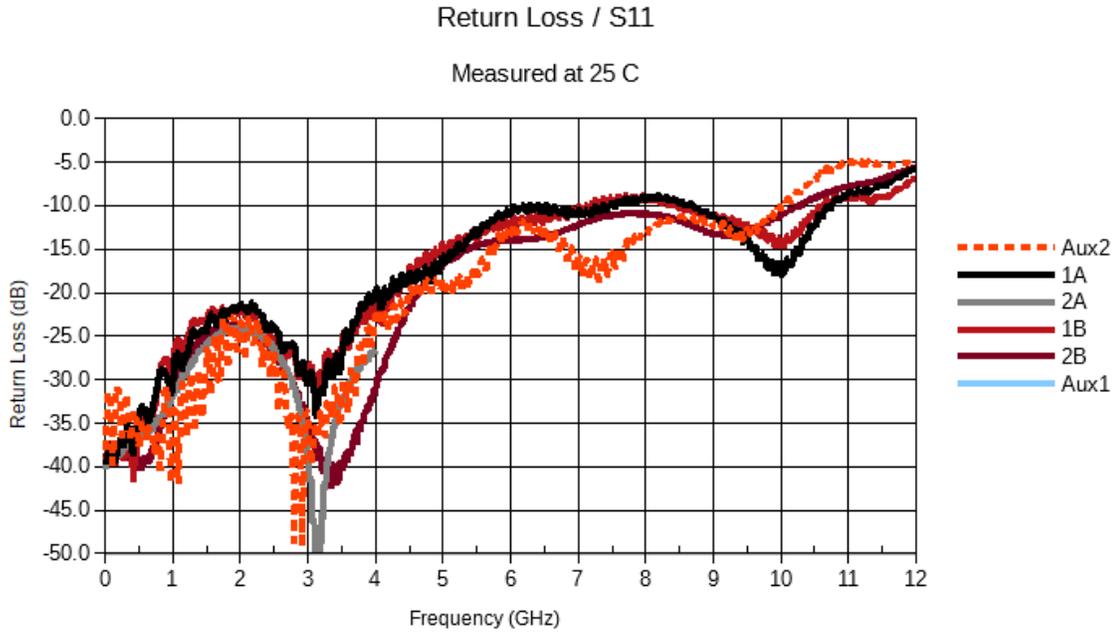


Figure 6. Single-ended Return Loss / S11

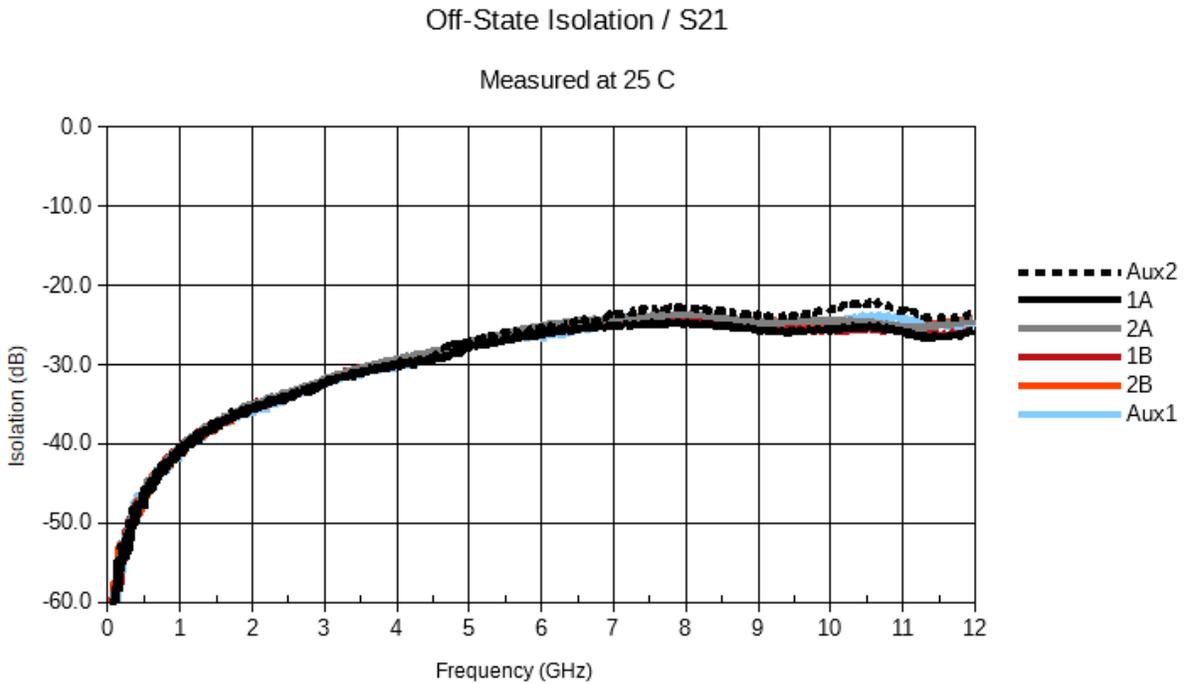


Figure 7. Single-ended Isolation / S21

Table 6. AC and DC Electrical Specifications¹

Parameter	Minimum	Typical	Maximum	Unit
On/Off Switching Time including Settling Time				
SettlingTime: on	—	8.5	16	μs
SettlingTime: off	—	2.5	6	μs
On/Off Switch Operations²	3x10 ⁹	30x10 ⁹	—	Cycles
Off-State Leakage Current³				
At 30 V _{DC}	—	3	100	nA
On-State Resistance (R_{On})	—	1.2	3.0	Ω
Off-State Capacitance (C_{Off})⁴	—	15	—	fF

Notes:

1. DC measurements were performed in single-ended configuration.
2. Specified at 25 °C ambient.
3. Measurement performed at 30V applied to RF input pin with corresponding RF output pins connected to ground.
4. Capacitance between input and output pins.

Hot Switch Restrictions

The MM5600 is not intended for hot switching applications and care should be taken to ensure that switching occurs at less than 0.5 V. Further, the voltage at the switch terminals must be within +/-0.5 V relative to RF ground.

Floating Node Restrictions

RF pins must not be allowed to electrically float during switch operation and therefore require some form of DC path to ground to prevent charge accumulation. DC paths can be an inductor or high value resistance which serves as a discharge path. Floating node examples are:

- Unconnected RF pins, resistively terminate or tie to ground.
- Series capacitance coupling which floats RF pin, shunt with DC path to ground.

See Menlo Micro application note **Avoiding Floating Nodes** for detailed explanation of the hazard conditions to avoid and recommended solutions.

Table 7. Driver DC Electrical Characteristics

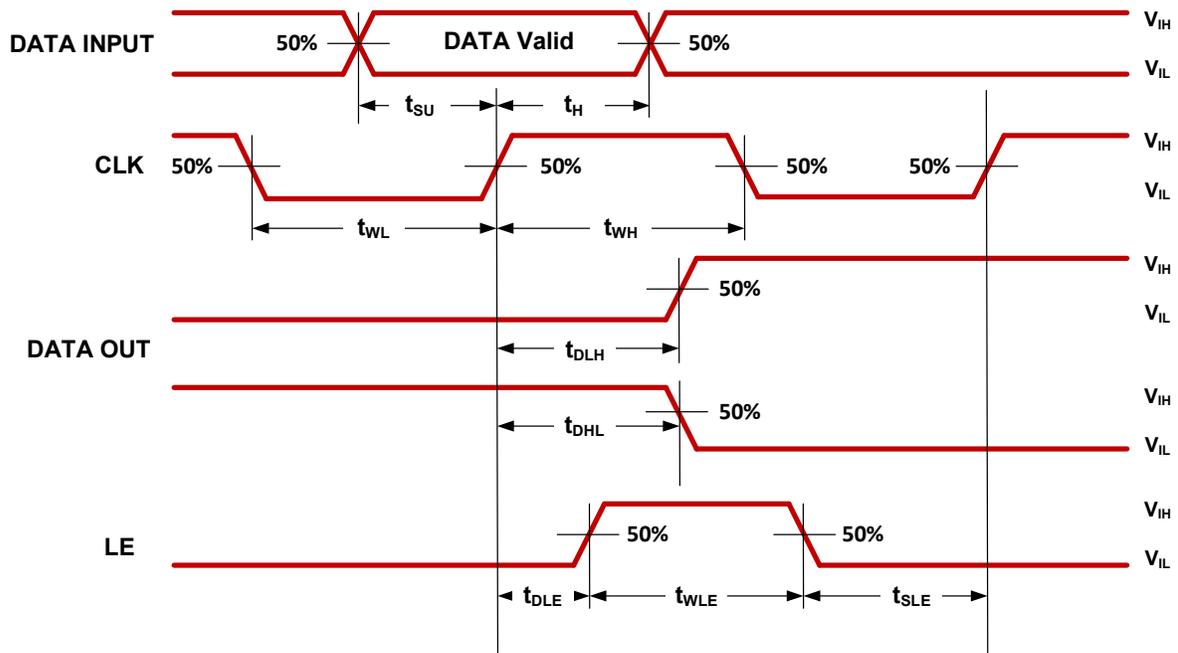
Parameter	Minimum	Typical	Maximum	Unit
Driver Logic Supply Current (I_{DD})¹	—	—	4	mA
Driver Input				
High-Level Logic Voltage V_{IH}	$V_{DD}-0.9V$	—	V_{DD}	V
Low-Logic Input Voltage V_{IL}	0	—	0.9	V
High-Logic Input Current I_{IH}	—	—	10	μA
Low-Logic Input Current I_{IL}	—	—	-350	μA
Driver Output				
High-Level Logic Output V_{OH} ²	$V_{DD}-1V$	—	—	V
Low-Level Logic Output V_{OL} ³	—	—	1	V
High-Voltage Bias Supply Current (I_{BB})⁴	—	—	10	μA

Notes:

1. Measured at $F_{clk} = 8$ MHz, LE = LOW
2. V_{OH} measured at $I_{DOUT} = -0.1$ mA
3. V_{OL} measured at $I_{DOUT} = -0.1$ mA
4. Measured at $V_{BB} = 100V$ and no load

Table 8. Driver AC Electrical Characteristics

Parameter	Minimum	Typical	Maximum	Unit
Clock Frequency f_{CLK}	0	—	8	MHz
Clock Width High and Low t_{WL}, t_{WH}	62	—	—	ns
Data Setup Time before Clock Rises t_{SU}	15	—	—	ns
Data Hold Time after Clock Rises t_H	30	—	—	ns
Latch Enable Pulse Width t_{WLE}	80	—	—	ns
Latch Enable Delay Time after Rising Edge of Clock t_{DLE}	35	—	—	ns
Latch Enable Setup Time before Clock Rises t_{SLE}	40	—	—	ns
Delay Time Clock to Data Low to High t_{DLH}	—	—	110	ns
Delay Time Clock to Data High to Low t_{DHL}	—	—	110	ns
Clock Frequency f_{CLK}	—	—	5	ns


Figure 8. Driver Interface Timing Diagram

Functional Block Diagram

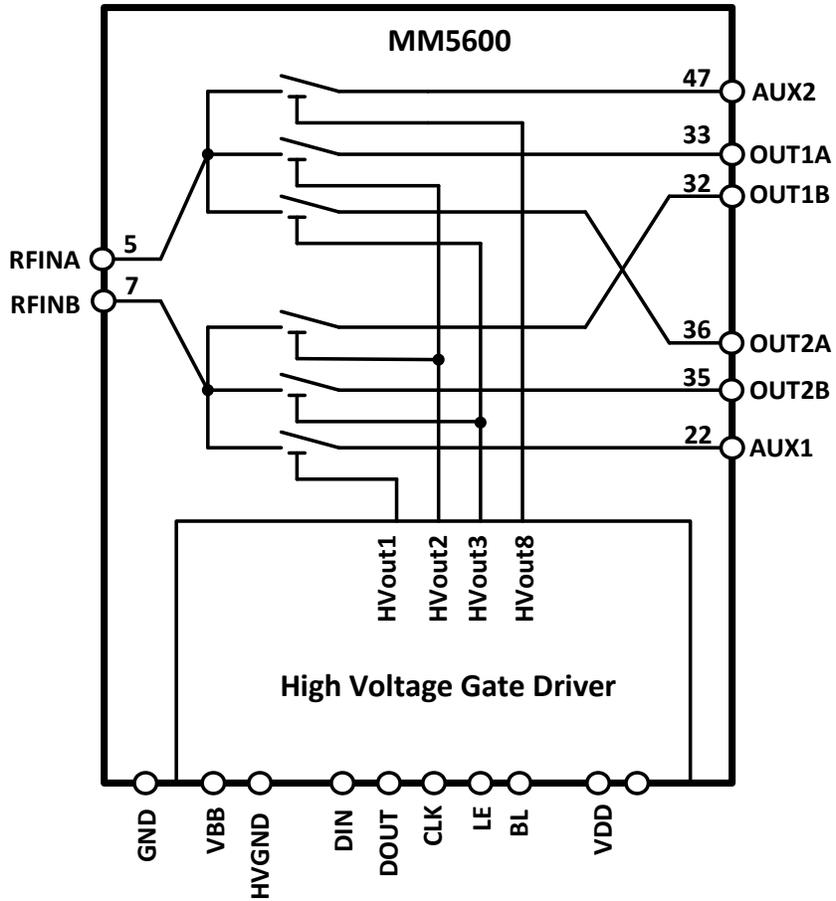


Figure 9. Functional Block Diagram

Package / Pinout Information

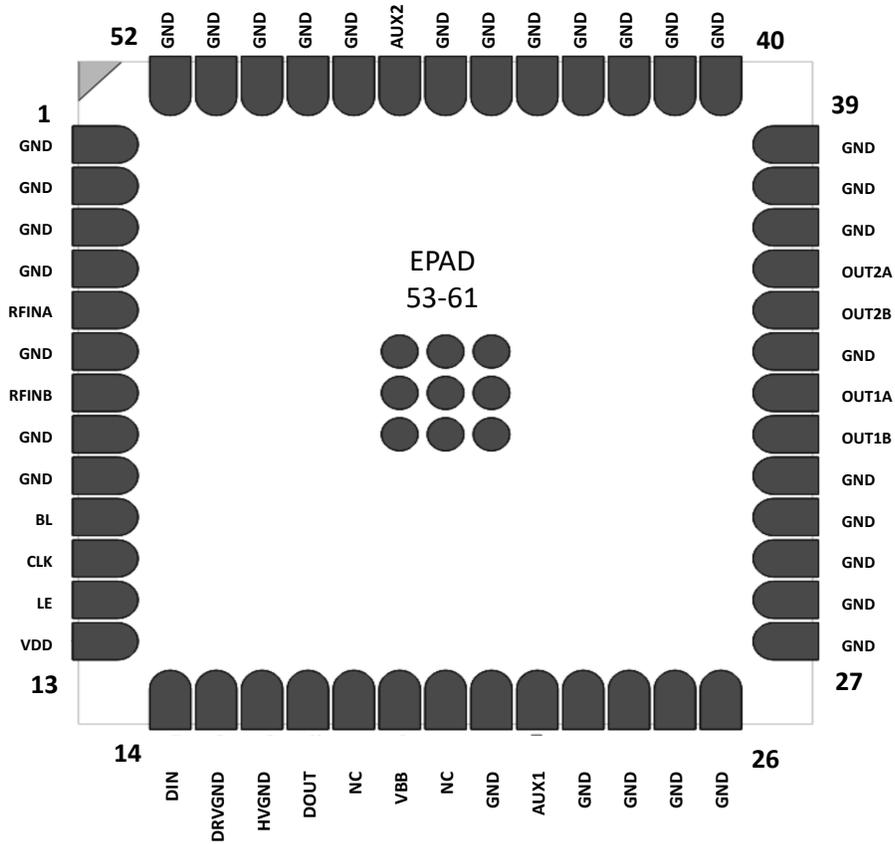


Figure 10. Top-Down Pin Layout

See [Table 9](#) for detailed pin description.

Table 9. Detailed Pin Description

Pin #	Pin Name	Description
1,2,3,4,6,8,9,21,23,24,25,26,27,28,29,30,31,34, 37,38,39,40,41,42,43,44,45,46,48,49,50,51,52	GND	RF Ground
53,54,55,56,57,58,59,60,61	EPAD	Tie these pins to GND
15	DRVGND	Driver Ground
16	HVGND	High Voltage Ground
11	CLK	Clock
10	BL	Blank
12	LE	Latch Enable
18,20	NC	No Connect
14	DIN	Data In
17	DOUT	Data Out
19	V _{BB}	High Voltage Supply
13	V _{DD}	Logic Supply Voltage
5	RFINA	Differential Input A
7	RFINB	Differential Input B
33	OUT1A	Differential Output 1A
32	OUT1B	Differential Output 1B
36	OUT2A	Differential Output 2A
35	OUT2B	Differential Output 2B
22	AUX1	Single-ended Output 1
47	AUX2	Single-ended Output 2

High Voltage Gate Driver Control

Operating Description

The integrated high voltage gate driver is controlled through a serial-to-parallel interface that drives the high voltage gate lines of the switches. Switch control data is shifted into an 8-bit shift register, latched, level translated, and applied as gate control signals as shown in [Figure 11](#).

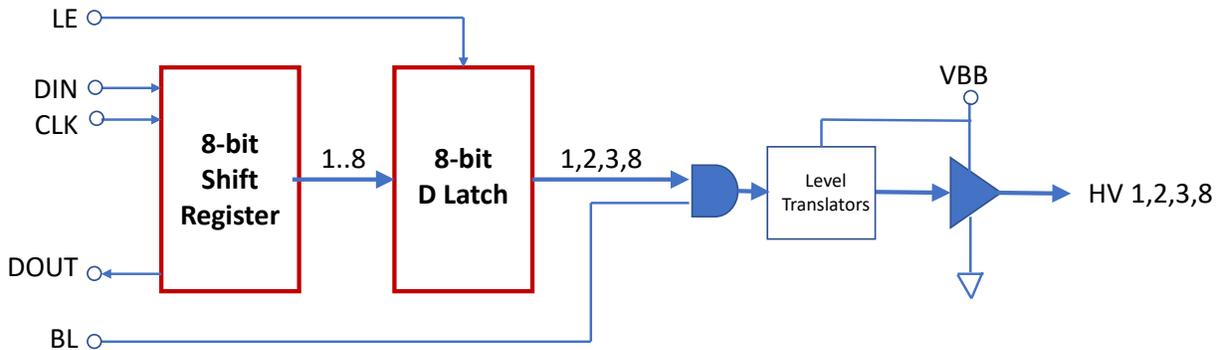


Figure 11. High Voltage Gate Driver Block Diagram

The gate driver is controlled by serial data input to DIN, sampled by CLK, latched by LE, and blanked by BL as follows:

- An 8-bit data byte is serially loaded into shift register bits 1-to-8 on the positive edge of CLK. Shift order is MSB first starting with bit 8.
- Parallel data from the shift register is transferred to the high voltage gate output buffers through an 8-bit D latch when the latch enable input LE is logically high. Transparent mode occurs when LE is held high while shifting data into the shift register.
- The MM5600 uses only four of the eight data bits latched for switch control. Bits 1, 2, and 3 and 8 correspond to high voltage gate lines HV1, HV2, HV3, and HV8 respectively. Bits 4,5,6 and 7 are not used. Data bits set to logical “1” close the corresponding switch to On and “0” open the switch to Off.
- Shift register data output pin DOUT may be used to cascade multiple devices by connecting DOUT of the first device to DIN of the next device. Other control signals should be shared between all the devices. In this case it is recommended to load 8-bit bytes consisting of 4 dummy bits and 4 switch control bits so that each byte controls one switch.
- There is no reset function. To clear register content, new data must be loaded.
- The blanking input BL will turn all gates off when logically low. The pin should be logically high for normal operation.
- Pins BL and LE have internal 20K ohm pull-up resistors to V_{DD}. If blanking is not used, BL may be unconnected.

Table 10. Truth Function Table

Function	Inputs				Shift Register		High Voltage Output HVx		
	Data	CLK	LE	BL	1	2 8	1	2 3	8
All off (blank)	X	X	X	L	*	*...*	L	L L - - - L	
Load Shift Register	H/L	↑	L	L	H/L	*...*	*	** - - - *	
Latched	X	X	L	L	*	*...*	*	** - - - *	
Transfer	H/L	X	H	H	H/L	*...*	H/L	** - - - *	

Notes:
H = High logic level
L = Low logic level
X = Don't care logic level
↑ = Low to high logic transition
*** = Dependent on the previous stage's state before the last CLK or last LE high**

Each switch is individually controllable. In [Table 11](#), primary usage states are highlighted in **bold**. Multiple branches may be closed simultaneously, however, RF performance is not specified for such states. Note that On= Closed, Off = Open.

Table 11. Applied Gate Voltage vs. RF Switch States

HV1	HV2	HV3	HV8	RFINA – OUT1A	RFINA – OUT2A	RFINB – AUX1	RFINB – OUT1B	RFINB – OUT2B	RFINA – AUX2
0	0	0	VBB	Off	Off	Off	Off	Off	On
0	0	VBB	0	Off	On	Off	Off	On	Off
0	VBB	0	0	On	Off	Off	On	Off	Off
VBB	0	0	0	Off	Off	On	Off	Off	Off
0	0	0	0	Off	Off	Off	Off	Off	Off
Other Valid States									
0	0	VBB	VBB	Off	On	Off	Off	On	On
0	VBB	0	VBB	On	Off	Off	On	Off	On
0	VBB	VBB	0	On	On	Off	On	On	Off
VBB	0	0	VBB	Off	Off	On	Off	Off	On
VBB	0	VBB	0	Off	On	On	Off	On	Off
VBB	VBB	0	0	On	Off	On	On	Off	Off
VBB	VBB	0	VBB	On	Off	On	On	Off	On
VBB	VBB	VBB	0	On	On	On	On	On	Off
VBB	VBB	VBB	VBB	On	On	On	On	On	On
0	VBB	VBB	VBB	On	On	Off	On	On	On
VBB	0	VBB	VBB	Off	On	On	Off	On	On

Package Drawing

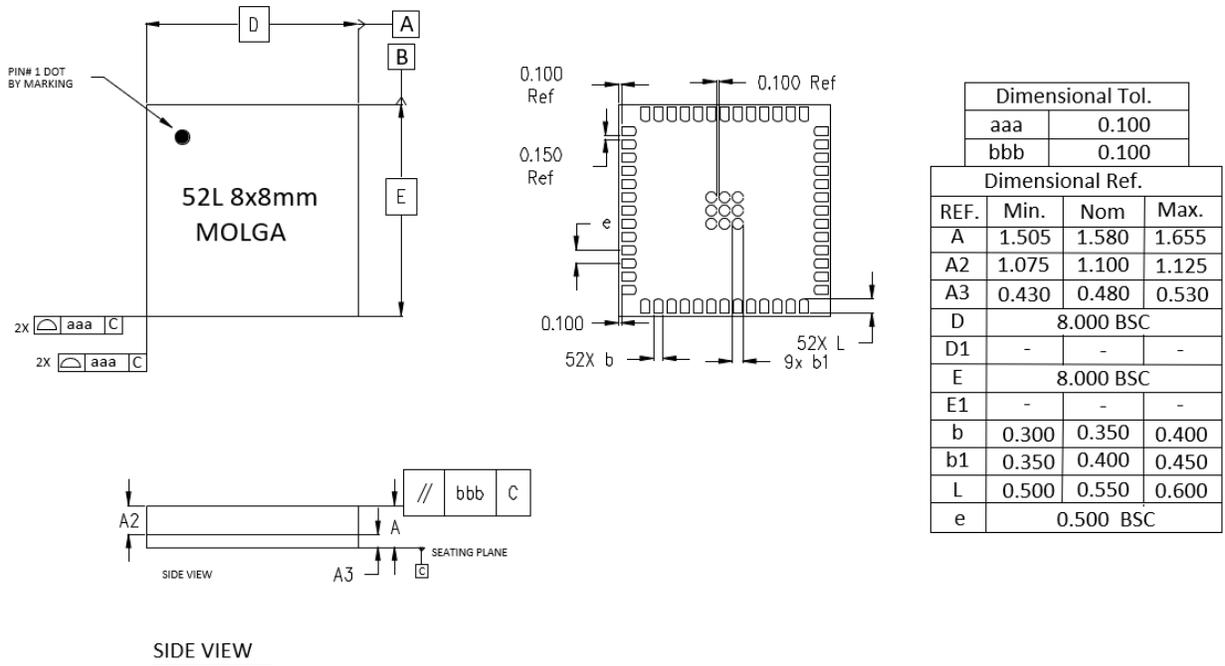


Figure 12. Package Drawing

The pin array is located symmetrically on the package body as specified in JEDEC Design Guide 4.25B for JEDEC LGA.

Recommended PCB Layout and SMT Parameters

- PCB lands should be as shown in the pad pattern diagram.
- Connect GND pins (floating shield inside the package) to RF Signal Ground.
- Open space around the package can have grounded thru holes.
- 20 micron (μm) thick solder mask
- Type 3 or higher solder paste with no clean flux
- Component placement force not to exceed 100 grams

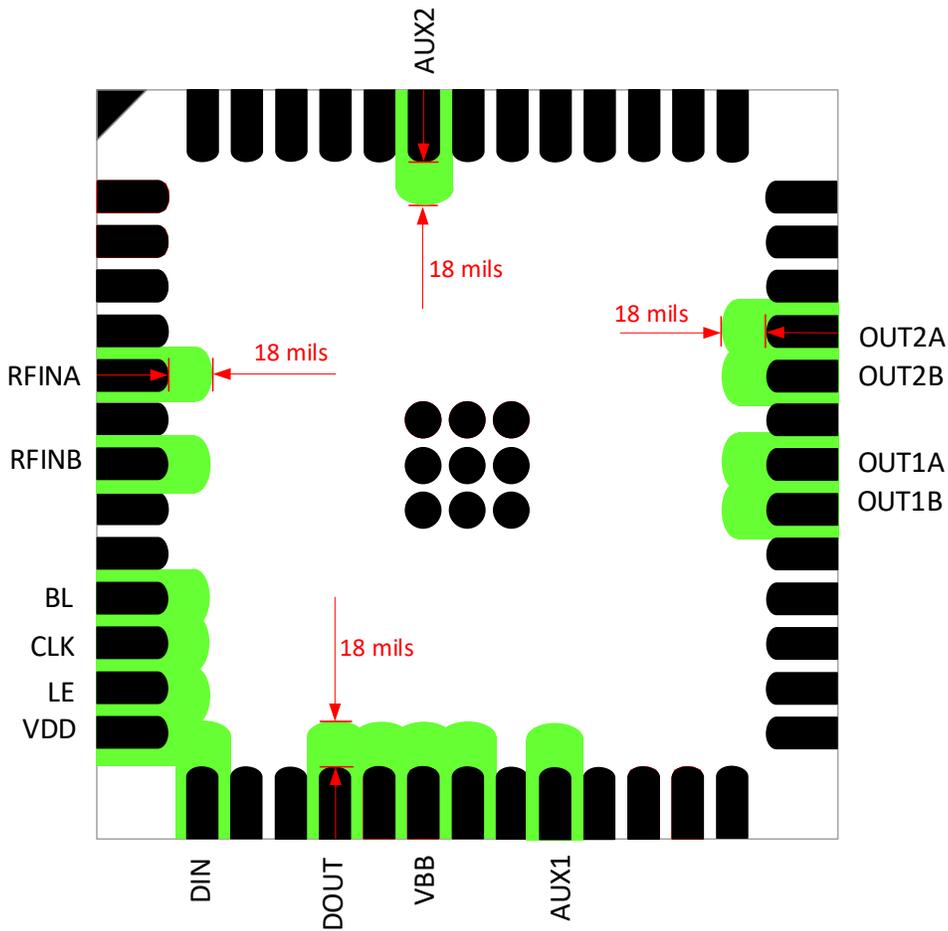


Figure 13. Example PCB Layout

Keep out the GND shape (green area) away from the RF PADS and IO signal PADS.

Recommended Solder Reflow Profile

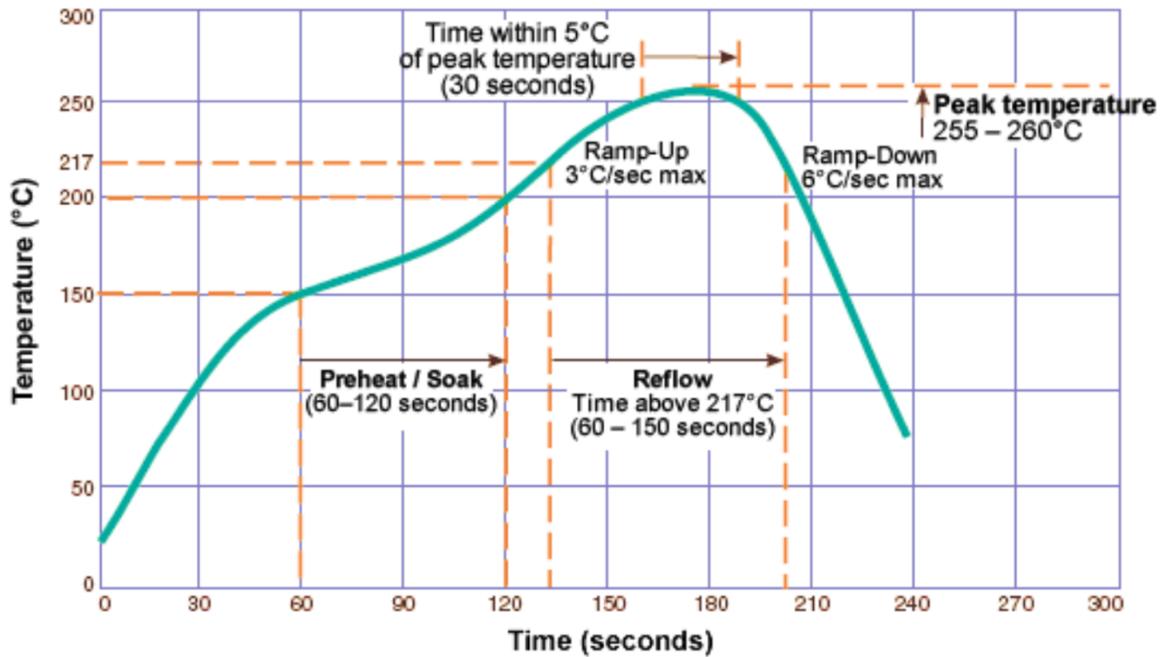


Figure 14. Reflow Profile

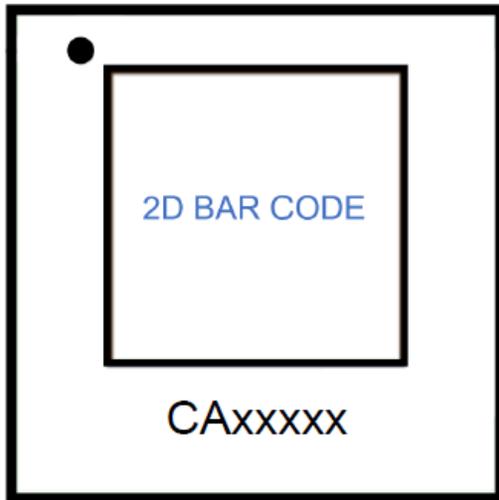
Follow Moisture Sensitivity Level (MSL) 3 handling precautions specified in IPC/JEDEC J-STD-020.

Storage and Shelf Life

Under typical industry storage conditions ($\leq 30^\circ\text{C}/60\% \text{RH}$) in Moisture Barrier Bags the following is recommended:

- Customer Shelf Life: 24 months from customer receipt date
- Extended Shelf Life: 60 months from customer receipt date if re-bagged every 24 months or less.
- Floor life: Moisture Sensitivity Level (MSL) testing is not required for Hermetic package as per JESD47K.

Package Marking Information



Dot ● = Pin 1 Indicator

Line 1 = 2D Bar Code

Line 2 = Human-readable product code

Figure 15. Package Marking Drawing

Package Options and Ordering Information

All Menlo Micro solutions are EAR99 compliant.

Part Number	Package Description	Temp Range	Device Marking ¹
MM5600-01NDB	DC-40Gbps - DPDT - 8mm x 8mm LGA ² , Industrial Temp	-40°C to +85°C	CAxxxxx
MM5600-01NDB-TR	DC-40Gbps - DPDT - 8mm x 8mm LGA ² , Industrial Temp, Tape and Reel (Qty 250)	-40°C to +85°C	CAxxxxx
MM5600EVK1	Evaluation board for MM5600 (differential crossover mode, w/Southwest connector-QTY-8) DC-40Gbps - DPDT - 8mm x 8mm LGA		
MM5600EVK1	Evaluation board for MM5600 (Dual SP3T single-ended mode, w/Rosenberger connector-QTY-10) DC-10GHz - Dual SP3T - 8mm x 8mm LGA		

Notes:

1. Additional markings may be present, including logo or lot trace code information. This information may be a 2D barcode or other human-readable markings. Note that 'x' is a placeholder for a 5-digit numerical code.

Legacy Product	New Product Name	
Name	Bulk	Tape and Reel ¹
MM5600-01	MM5600-01NDB	MM5600-01NDB-TR

Notes:

1. 250pcs standard tape and reel increment.

Important Information

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